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SCS206AJ

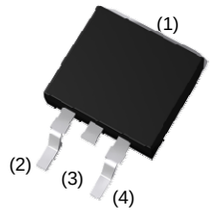
SiC Schottky Barrier Diode

Datasheet

V_R	650V
I_F	6A
Q_C	9nC

●Outline

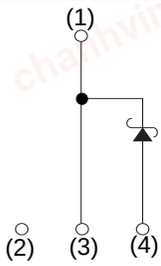
LPT(L)
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●Features

1) Shorter recovery time
2) Reduced temperature dependence
3) High-speed switching possible

●Inner circuit



(1) Cathode
(2) N / C
(3) Cathode
(4) Anode

●Applications

- PFC Boost Topology
- Secondary Side Rectification
- Data Center
- PV Power Conditioners

●Packaging specifications

Type	Packaging	Embossed tape
	Reel size (mm)	330
	Tape width (mm)	24
	Basic ordering unit (pcs)	1 000
	Packing code	TLL
	Marking	SCS206AJ

●Absolute maximum ratings (T_j = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (repetitive peak)		V_{RM}	650	V
Reverse voltage (DC)		V_R	650	V
Continuous forward current (T_c= 136°C)		I_F	6	A
Surge non-repetitive forward current	PW=10ms sinusoidal, T_j=25°C	I_{FSM}	23	A
	PW=10ms sinusoidal, T_j=150°C		18	A
	PW=10μs square, T_j=25°C		90	A
Repetitive peak forward current		I_{FRM}	26 *1	A
i^2t value	PW=10ms, T_j=25°C	$\int i^2dt$	2.6	A^2s
	PW=10ms, T_j=150°C		1.6	A^2s
Total power dissipation		P_D	48 *2	W
Junction temperature		T_j	175	°C
Range of storage temperature		T_{stg}	−55 to +175	°C

*1 T_c=100°C, T_j=150°C, Duty cycle=10% *2 T_c=25°C

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●Electrical characteristics (T_j = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
DC blocking voltage	V_{DC}	I_R =1.2mA	650	-	-	V
Forward voltage	V_F	I_F=6A,T_j=25°C	-	1.35	1.55	V
		I_F=6A,T_j=150°C	-	1.55	-	V
		I_F=6A,T_j=175°C	-	1.63	-	V
Reverse current	I_R	V_R=600V,T_j=25°C	-	1.2	120	μA
		V_R=600V,T_j=150°C	-	18	-	μA
		V_R=600V,T_j=175°C	-	42	-	μA
Total capacitance	C	V_R=1V,f=1MHz	-	220	-	pF
		V_R=600V,f=1MHz	-	22	-	pF
Total capacitive charge	Q_C	V_R=400V,di/dt=350A/μs	-	9	-	nC
Switching time	t_C	V_R=400V,di/dt=350A/μs	-	12	-	ns

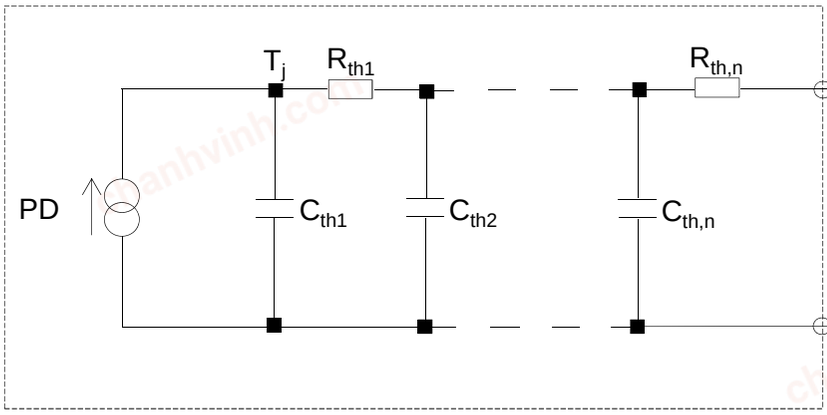
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Thermal resistance	$R_{th(j-c)}$	-	-	2.3	3.1	°C/W

●Typical Transient Thermal Characteristics

Symbol	Value	Unit
R_{th1}	2.28E-01	K/W
R_{th2}	1.53E+00	
R_{th3}	5.41E-01	

Symbol	Value	Unit
C_{th1}	1.05E-03	Ws/K
C_{th2}	4.56E-04	
C_{th3}	1.28E-02	



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●Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

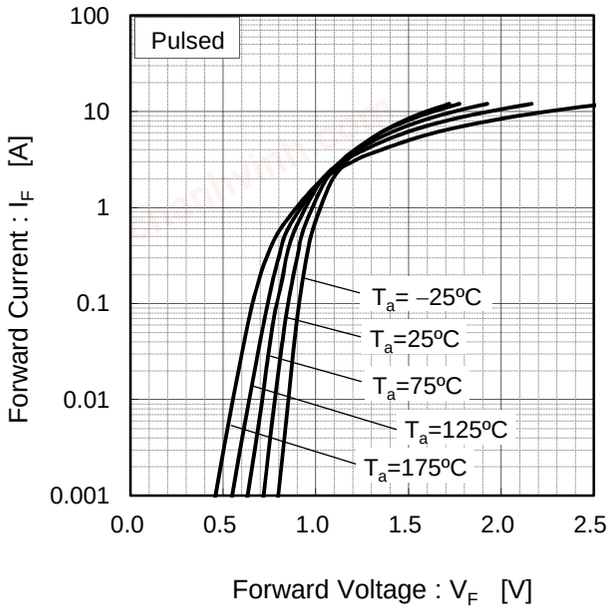


Fig.2 V_F - I_F Characteristics

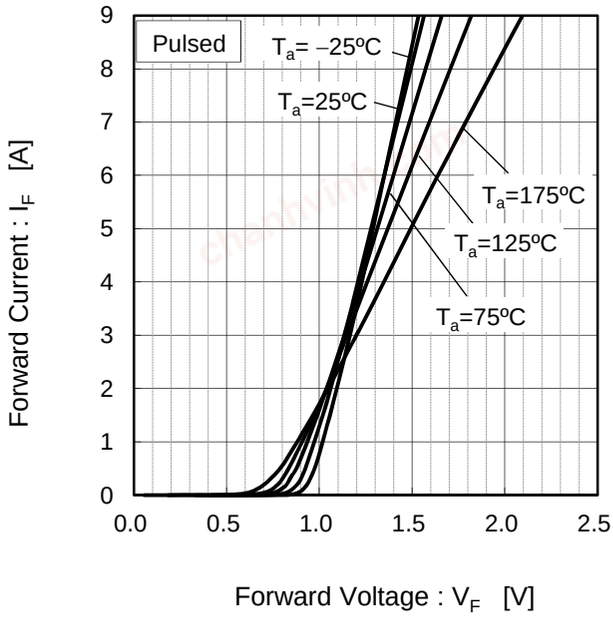


Fig.3 V_R - I_R Characteristics

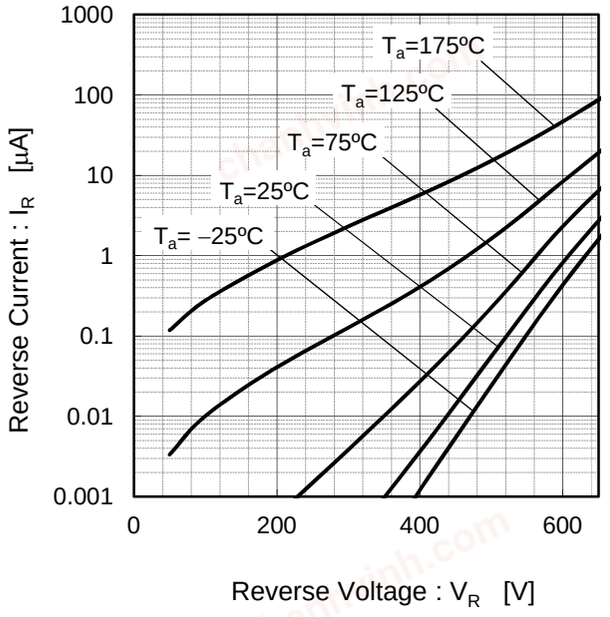
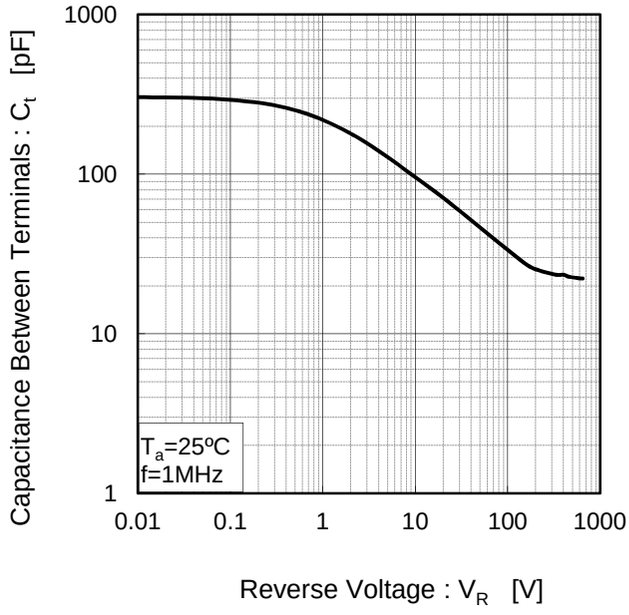


Fig.4 V_R - C_t Characteristics



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●Electrical characteristic curves

Fig.5 Typical Transient Thermal Resistance vs. Pulse Width

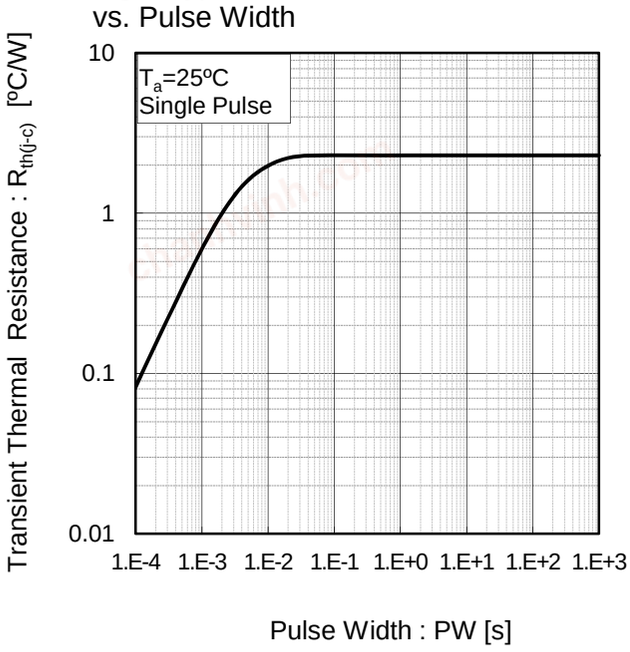


Fig.6 Power Dissipation

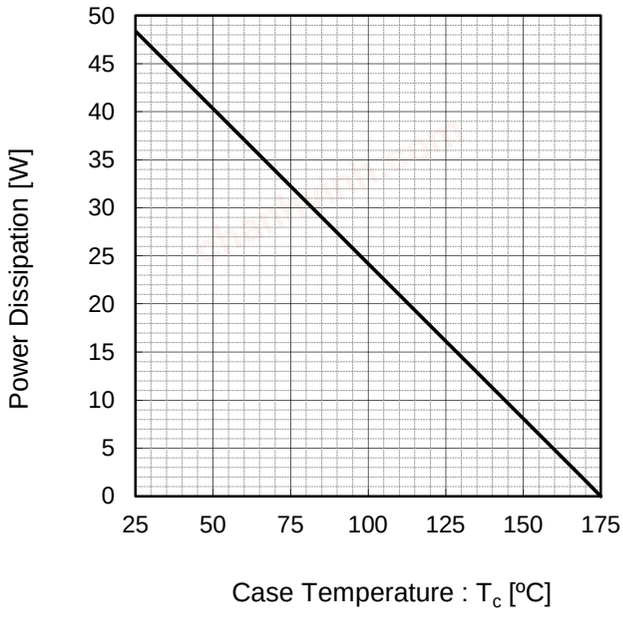
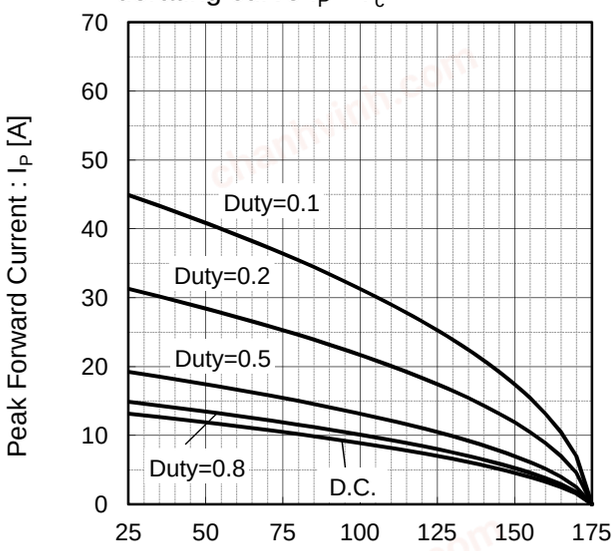
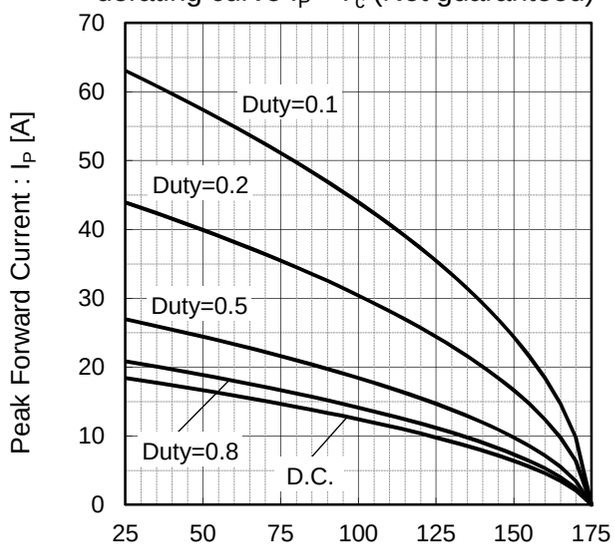


Fig.7*3 Maximum peak forward current derating curve I_P - T_c



*3 Based on max Vf, max $R_{th(j-c)}$
Valid for switching of above 10kHz, excluding D.C. curve.

Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)



*4 Based on typ Vf, typ $R_{th(j-c)}$
Typical value, not guaranteed
Valid for switching of above 10kHz, excluding D.C. curve

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●Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)

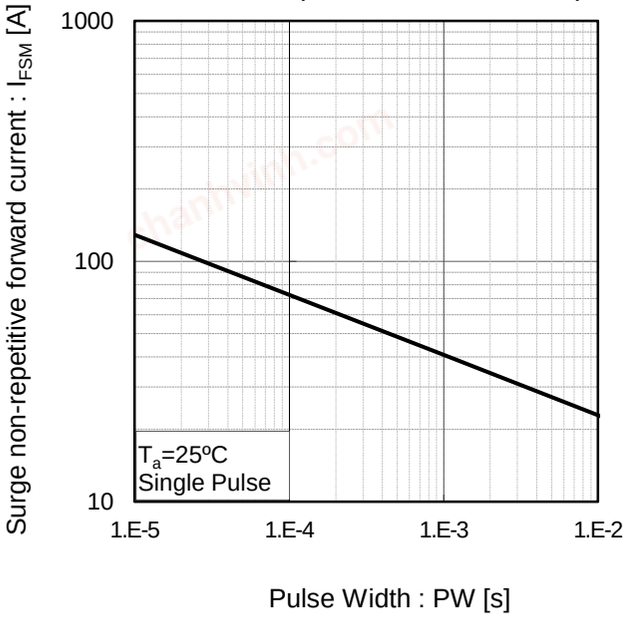
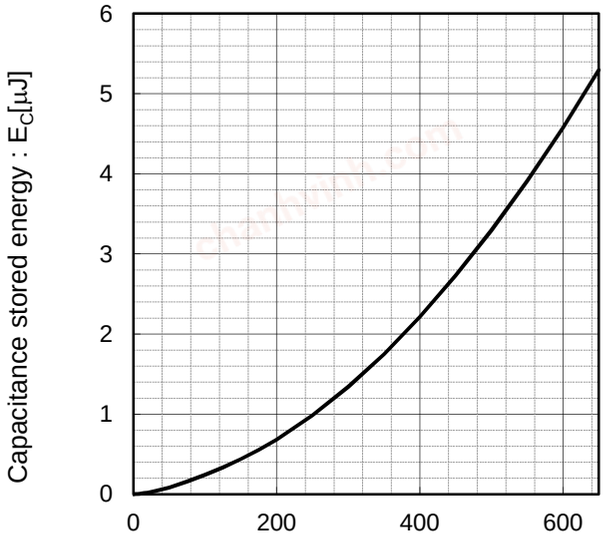
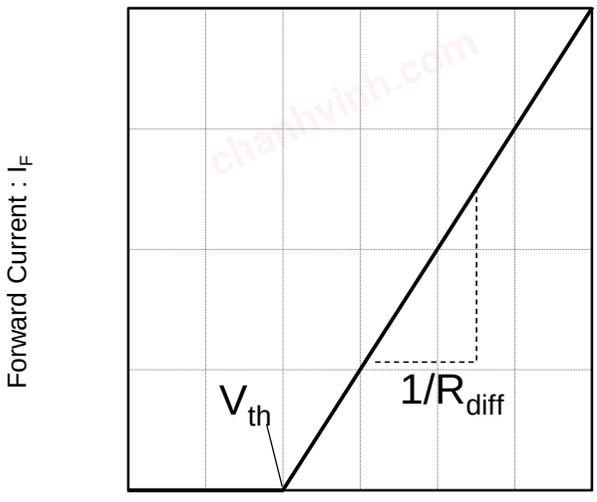


Fig.10 Typical capacitance store energy



●Symplified forward characteristic model

Fig.11 Equivalent forward current curve



$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th}(T_j) = a_0 + a_1 T_j$$
$$R_{diff}(T_j) = b_0 + b_1 T_j + b_2 T_j^2$$

Symbol	Typical Value	Unit
a_0	9.35E-01	V
a_1	-1.12E-03	V/°C
b_0	6.63E-02	Ω
b_1	1.70E-04	Ω/°C
b_2	1.80E-06	Ω/°C^2

T_j in ºC; -55 ºC < T_j < ºC ; I_F < 12 A

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